

LF21904N

High-Side / Low-Side Gate Driver

Features

- Floating high-side driver in bootstrap operation to 600V
- Drives two N-channel MOSFETs or IGBTs in a half-bridge configuration
- Output drivers capable of 4.5A/4.5A typ sink/source
- Logic input (HIN and LIN) 3.3V capability
- Schmitt triggered logic inputs with internal pulldown
- Under Voltage Lockout (UVLO) for high and low-side drivers
- Extended temperature range: -40°C to +125°C

Description

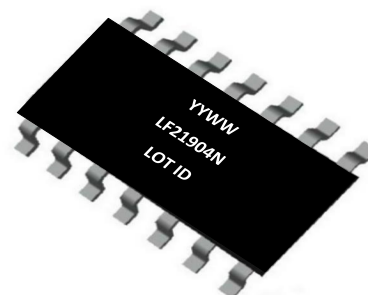
The LF21904N is a high voltage, high speed gate driver capable of driving N-channel MOSFET's and IGBTs in a half-bridge configuration. The high voltage technology enables the LF21904N's high side to switch to 600V in a bootstrap operation under high dV/dt conditions.

LF21904N logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction.

LF21904N is offered in the 14-pin SOIC and operates over the extended temperature range of -40°C to +125°C.

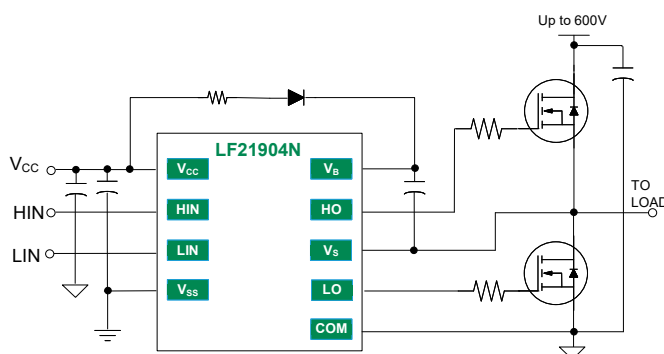
Applications

- Motor Controls
- DC-DC Converters
- AC-DC Inverters
- Class D Power Amplifiers



SOIC(N)-14

Typical Application



Ordering Information

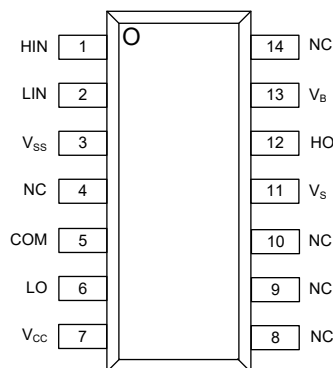
Year Year Week Week

Part #	Package	Pack / Qty	Mark
LF21904NTR	SOIC(N)-14	T&R / 2500	YYWW LF21904N Lot ID



1 Specifications

1.1 Pin Diagrams



Top View: SOIC(N)-14
LF21904N

1.2 Pin Descriptions

Pin #	Pin Name	Pin Type	Description
1	HIN	Input	Logic input for high-side gate driver output, in phase with HO
2	LIN	Input	Logic input for low-side gate driver output, in phase with LO
3	V _{ss}	Power	Logic Ground
5	COM	Power	Low-side and logic return
6	LO	Output	Low-side gate drive output
7	V _{cc}	Power	Low-side and logic fixed supply
11	V _s	Power	High-side floating supply return
12	HO	Output	High-side gate driver output
13	V _b	Power	High-side floating supply
4, 8, 9, 10, 14	NC	No Connect	Not connected internally

1.3 Absolute Maximum Ratings

Parameter	Symbol	Min	Max	Unit
High side floating supply voltage	V_B	-0.3	+624	V
High side floating supply offset voltage	V_S	$V_B - 24$	$V_B + 0.3$	V
Logic Supply offset voltage	V_{SS}	$V_{CC} - 24$	$V_{CC} + 0.3$	V
High side floating output voltage	V_{HO}	$V_S - 0.3$	$V_B + 0.3$	V
Offset supply voltage transient	dV_S/dt	--	50	V/ns
Low side fixed supply voltage	V_{CC}	-0.3	+24	V
Low side output voltage	V_{LO}	-0.3	$V_{CC} + 0.3$	V
Logic input voltage (HIN and LIN)	V_{IN}	$V_{SS} - 0.3$	$V_{CC} + 0.3$	V
Package power dissipation	P_D	--	1	W
Junction Operating Temperature	T_J	--	+150	°C
Storage Temperature	T_{STG}	-55	+150	°C

Unless otherwise specified all voltages are referenced to COM . All electrical ratings are at $T_A = 25^\circ\text{C}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

1.4 Thermal Characteristics

Parameter	Symbol	Rating	Unit
Junction to ambient	θ_{JA}	120	°C/W

When mounted on a standard JEDEC 2-layer FR-4 board - JESD51-3

1.5 Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High side floating supply absolute voltage	V_B	$V_S + 10$	$V_S + 20$	V
High side floating supply offset voltage	V_S	NOTE1	600	
Logic ground	V_{SS}	-5	5	
High side floating output voltage	V_{HO}	V_S	V_B	
Low side fixed supply voltage	V_{CC}	10	20	
Low side output voltage	V_{LO}	0	V_{CC}	
Logic input voltage (HIN and LIN)	V_{IN}	V_{SS}	$V_{SS} + 5$	
Ambient temperature	T_A	-40	125	°C

Unless otherwise specified all voltages are referenced to COM

NOTE1 High-side driver remains operational for V_S transients down to -5V

1.6 DC Electrical Characteristics

$V_{CC} = V_{BS} = 15V$, $T_A = 25^\circ C$ and $V_{SS} = V_{COM} = 0V$, unless otherwise specified.

The V_{IN} and I_{IN} parameters are applicable to both logic input pins: HIN and LIN. The V_O and I_O parameters are applicable to the respective output pins: HO and LO and are referenced to COM

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Logic "1" input voltage	V_{IH}	$V_{CC} = 10V$ to $20V$	2.5	--	--	V
Logic "0" input voltage	V_{IL}	NOTE2	--	--	0.8	
Logic input voltage hysteresis	$V_{IN(HYS)}$	--	--	0.3	--	
High level output voltage, $V_{BIAS} - V_O$	V_{OH}	$I_O = 0mA$	--	--	0.1	
Low level output voltage, V_O	V_{OL}	$I_O = 0mA$	--	--	0.035	
Offset supply leakage current	I_{LK}	$V_B = V_S = 600V$	--	--	50	μA
Quiescent V_{BS} supply current	I_{BSQ}	$V_{IN} = 0V$ or $5V$	--	45	80	
Quiescent V_{CC} supply current	I_{CCQ}	$V_{IN} = 0V$ or $5V$	--	75	200	
Logic "1" input bias current	I_{IN+}	$V_{IN} = 5V$	--	25	50	
Logic "0" input bias current	I_{IN-}	$V_{IN} = 0V$	--	1.0	2.0	
V_{BS} UVLO off positive going threshold	V_{BSUV+}	--	7.6	8.4	9.8	V
V_{BS} UVLO enable negative going threshold	V_{BSUV-}	--	6.9	7.8	9.0	
V_{BS} UVLO hysteresis	$V_{BSUV(HYS)}$	--	--	0.6	--	
V_{CC} UVLO off positive going threshold	V_{CCUV+}	--	7.6	8.4	9.8	
V_{CC} UVLO enable negative going threshold	V_{CCUV-}	--	6.9	7.8	9.0	
V_{CC} UVLO hysteresis	$V_{CCUV(HYS)}$	--	--	0.6	--	A
Output high short circuit pulsed current	I_{O+}	$V_O = 0V$, $t \leq 10 \mu s$	3.5	4.5	--	
Output low short circuit pulsed current	I_{O-}	$V_O = 15V$, $t \leq 10 \mu s$	3.5	4.5	--	

NOTE2 For optimal operation, it is highly recommended the input pulse (to HIN and LIN) should have a minimum amplitude of 2.5V with a minimum pulse width of 280ns.

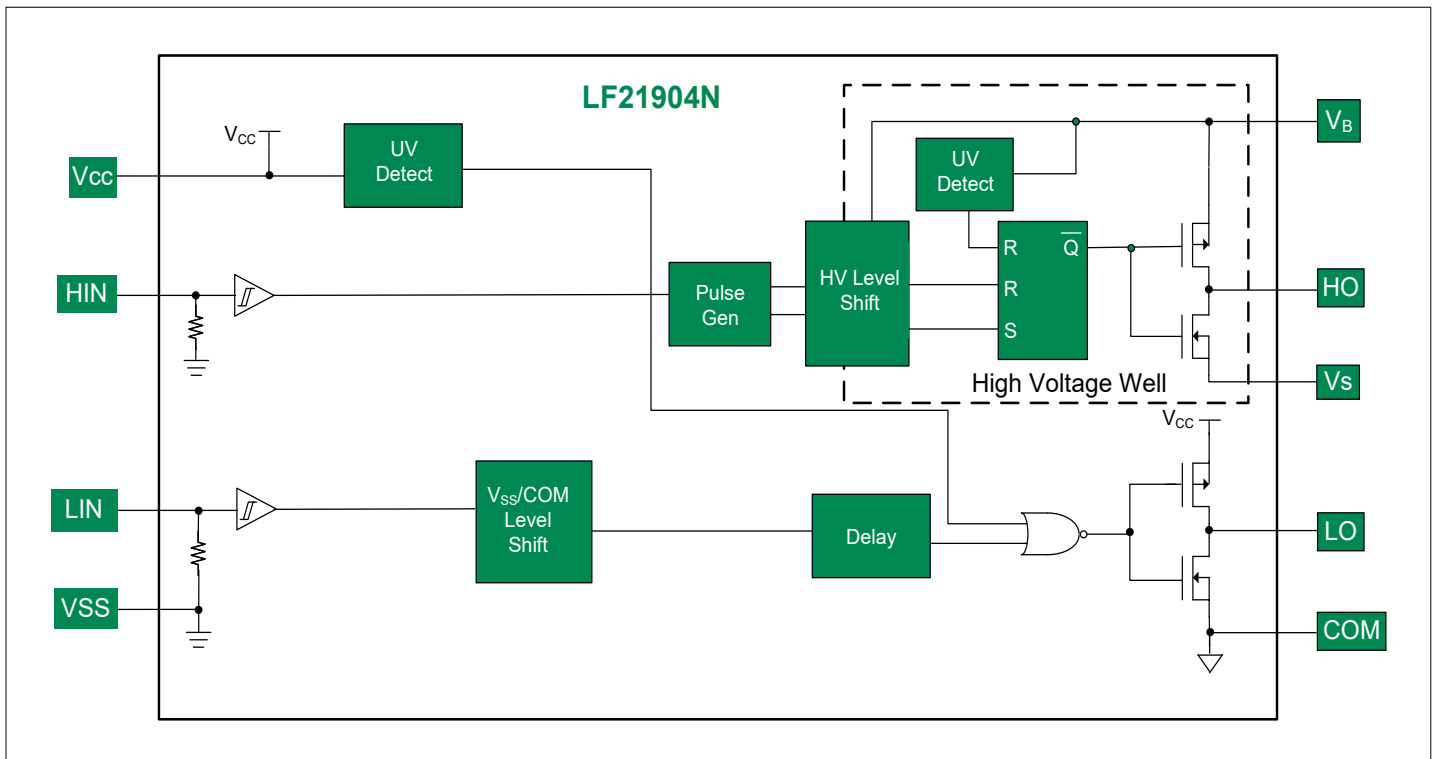
1.7 AC Electrical Characteristics

$V_{CC}=V_{BS}=15V$, $V_{SS}=V_{COM}=0V$, $C_L=1000pF$, and $T_A=25^\circ C$, unless otherwise specified.

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Turn-on propagation delay	t_{on}	$V_S=0V$	--	140	200	ns
Turn-off propagation delay	t_{off}	$V_S=0V$	--	140	200	
Propagation delay matching, HO & LO turn on/off	t_{DM}	--	--	0	50	
Turn-on rise time	t_r	$V_S=0V$	--	25	50	
Turn-off fall time	t_f		--	20	45	

2 Functional Description

2.1 Functional Block Diagram



2.2 Timing Waveforms

Figure 1. Input / Output Logic Diagram

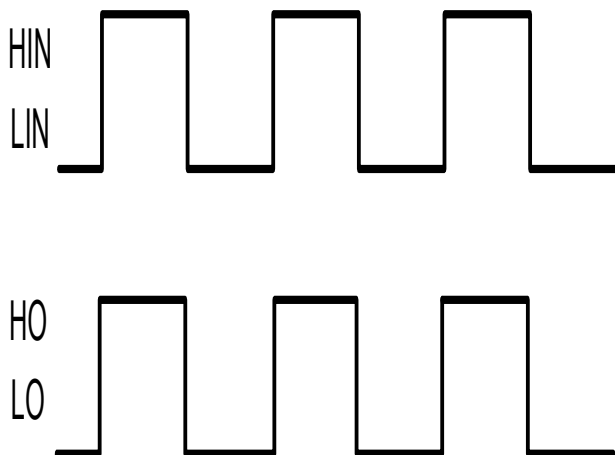


Figure 2. Propagation Delay Matching

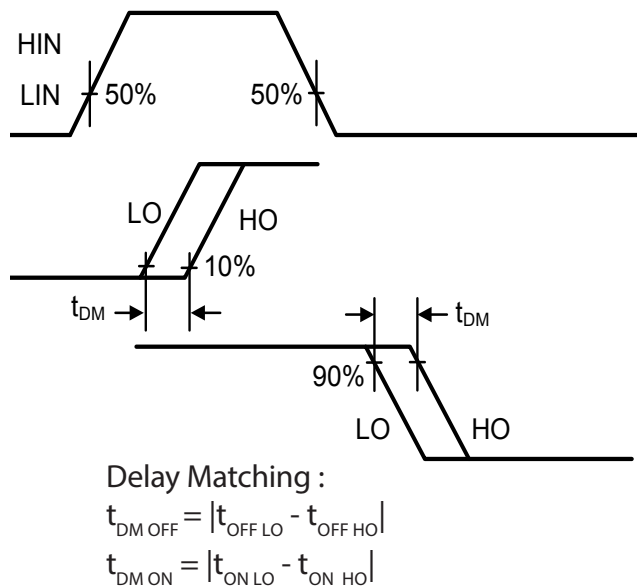
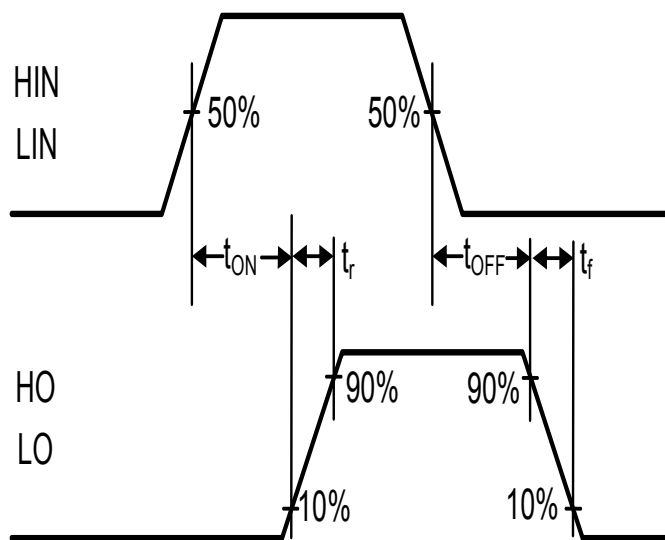


Figure 3. Input-to-Output Delay Timing Diagram



2.3 Application Information

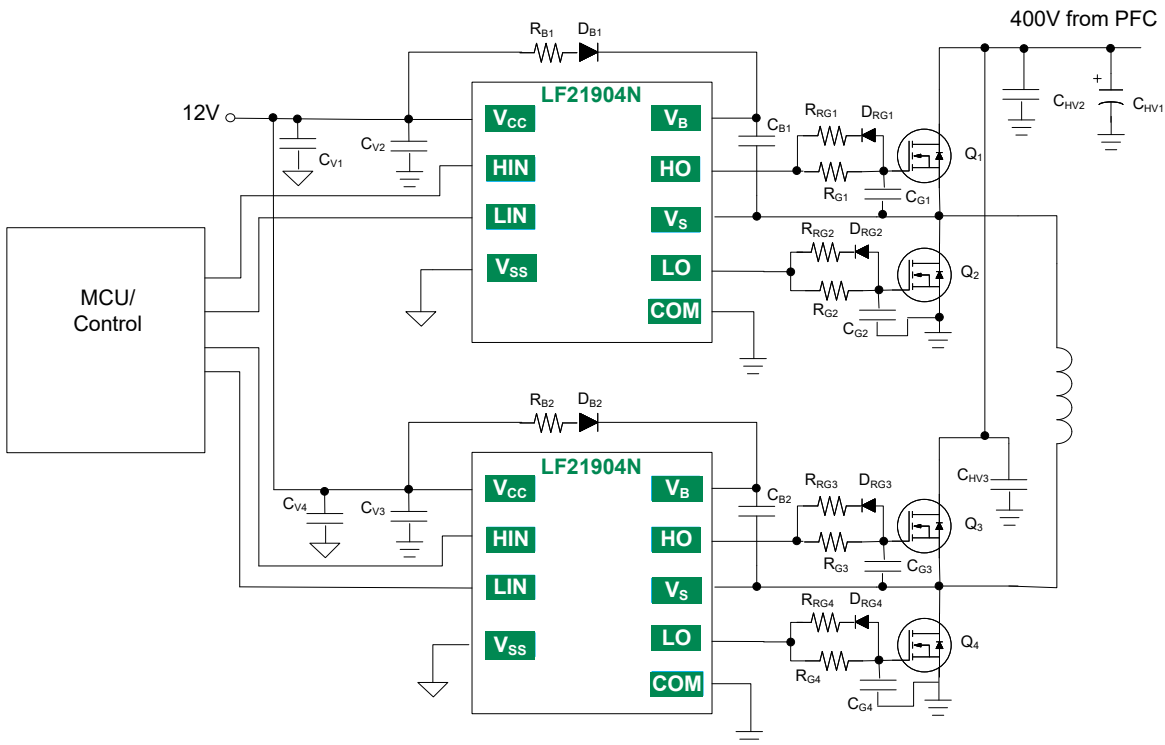


Figure 4. Primary side of Full Bridge converter using LF21904N

- RRG1, RRG2, RRG3, and RRG4 values are typically between 0Ω and 10Ω, exact value decided by MOSFET junction capacitance and drive current of gate driver; 10Ω is used in this example.
- It is **highly recommended** that the input pulse (to HIN and LIN) should have a minimum amplitude of 2.5V (for $V_{CC}=15V$) with a minimum pulse width of 280ns.
- RG1, RG2, RG3, and RG4 values are typically between 20Ω and 100Ω, exact value decided by MOSFET junction capacitance and drive current of gate driver; 50Ω is used in this example.
- RB1 and RB2 value is typically between 3Ω and 20Ω, exact value depending on bootstrap capacitor value and amount of current limiting required for bootstrap capacitor charging; 10Ω is used in this example. Also DB1 and DB2 should be an ultra fast diode of 1A rating minimum and voltage rating greater than system operating voltage.

3 Performance Data

Unless otherwise noted $V_{CC} = V_{BS} = 15V$, $T_A = 25^\circ C$, $V_{SS} = V_{COM} = 0V$ and values are typical.

Figure 5. Turn-on Propagation Delay vs. Supply Voltage

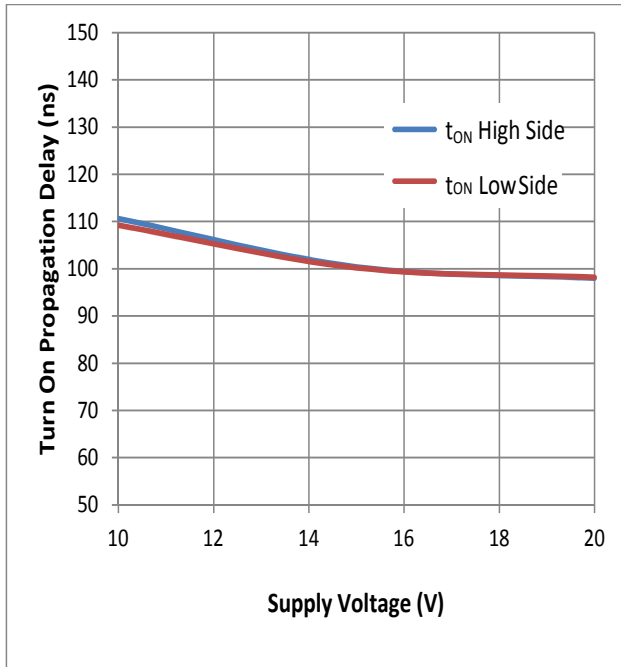


Figure 6. Turn-on Propagation Delay vs. Temperature

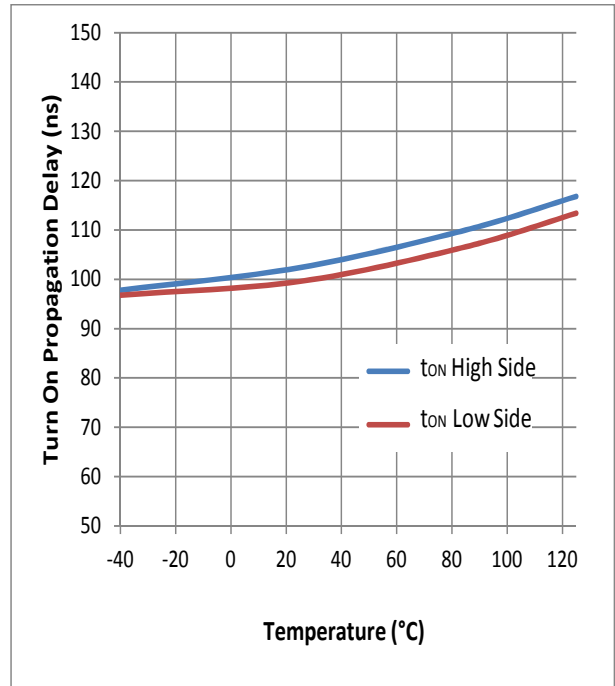


Figure 7. Turn-off Propagation Delay vs. Supply Voltage

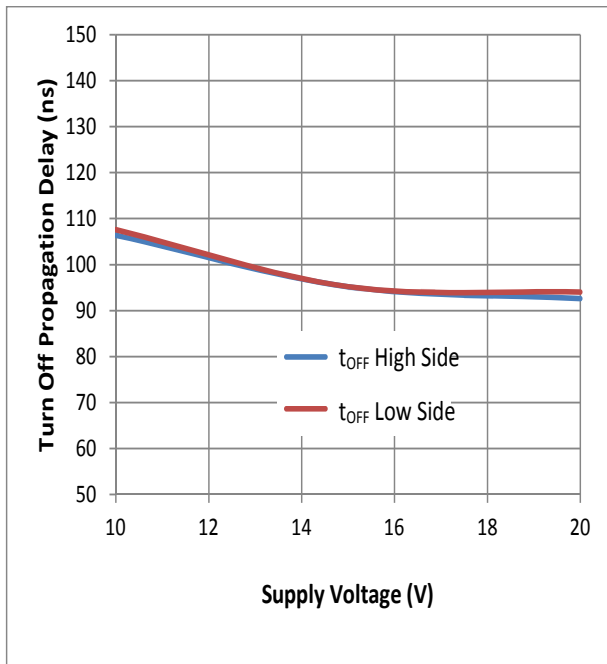


Figure 8. Turn-off Propagation Delay vs. Temperature

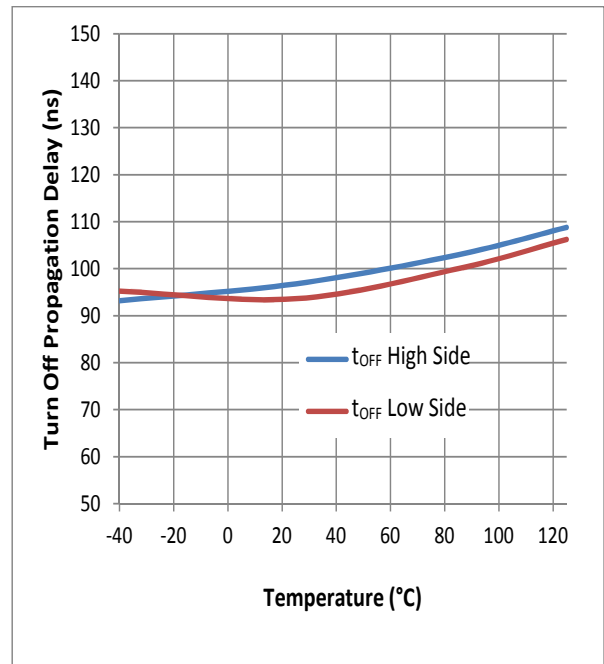


Figure 9. Rise Time vs. Supply Voltage

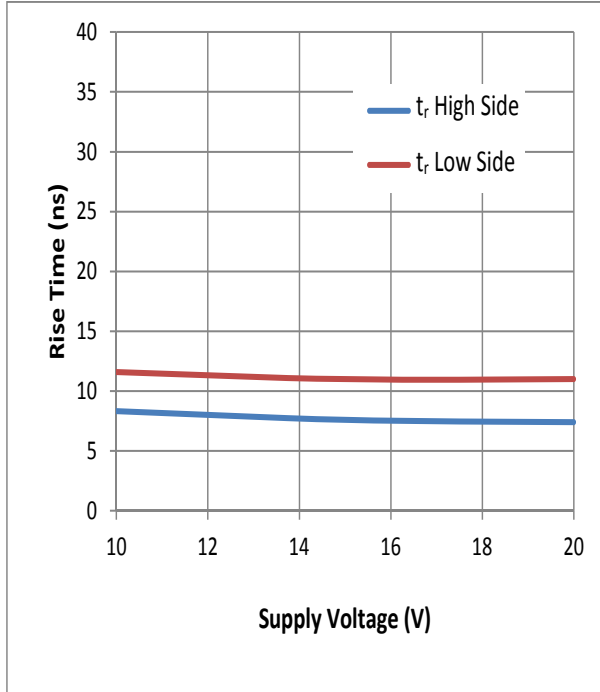


Figure 10. Rise Time vs. Temperature

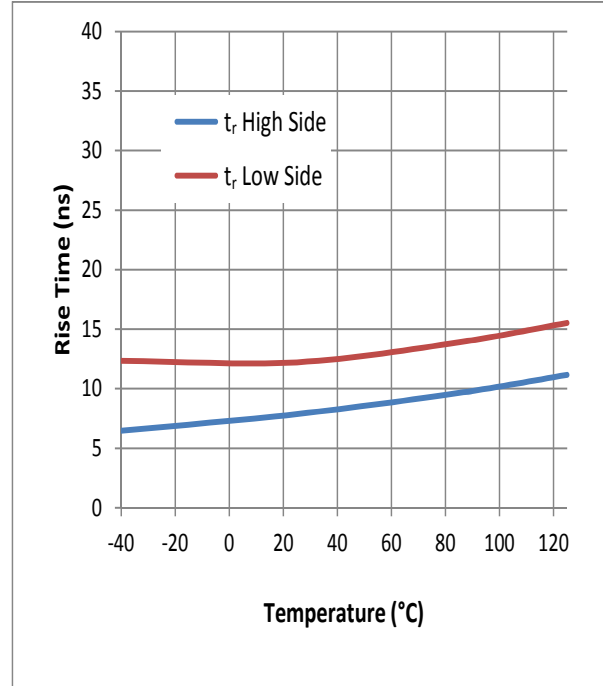


Figure 11. Fall Time vs. Supply Voltage

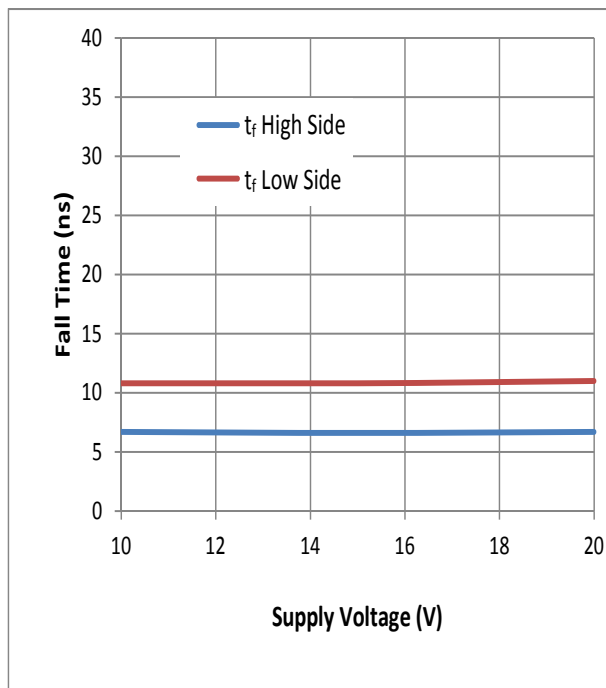


Figure 12. Fall Time vs. Temperature

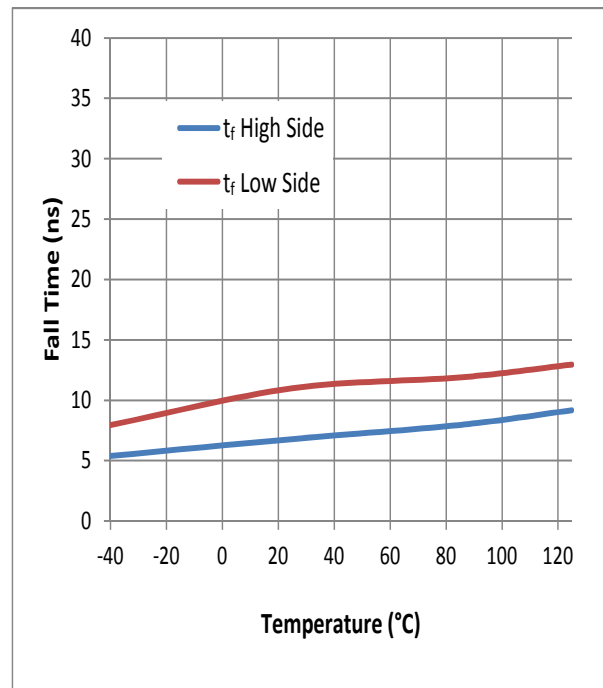


Figure 13. Delay Matching vs. Supply Voltage

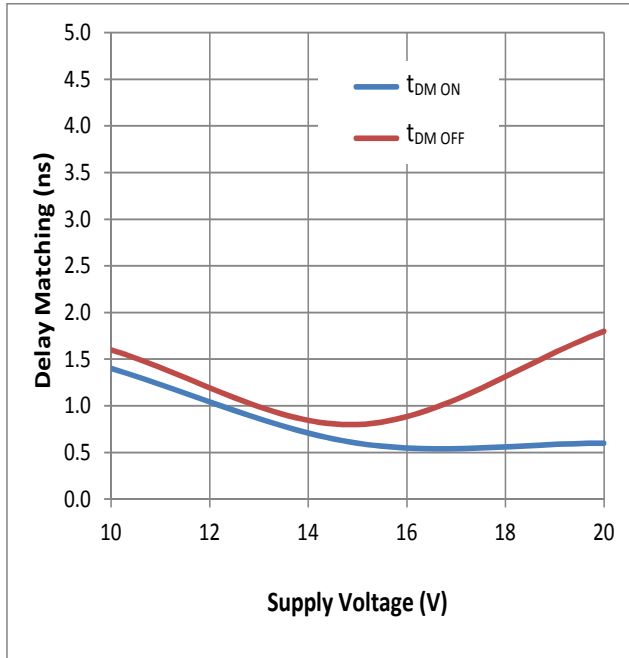


Figure 14. Delay Matching vs. Temperature

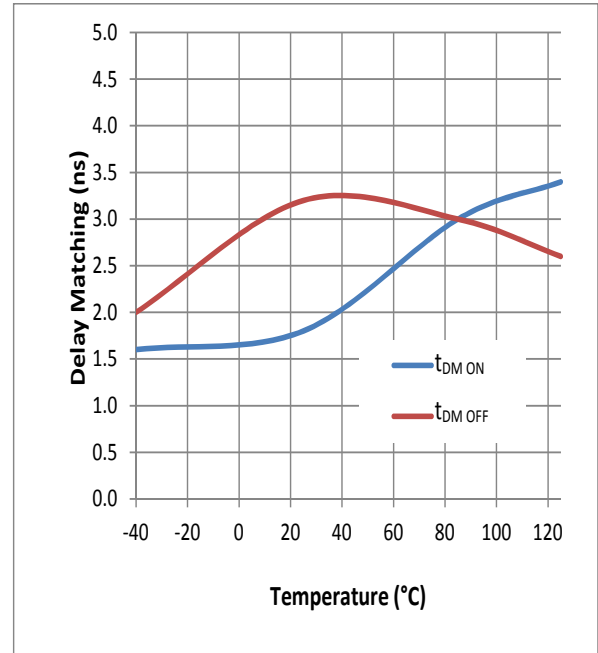


Figure 15. Output Source Current vs. Supply Voltage

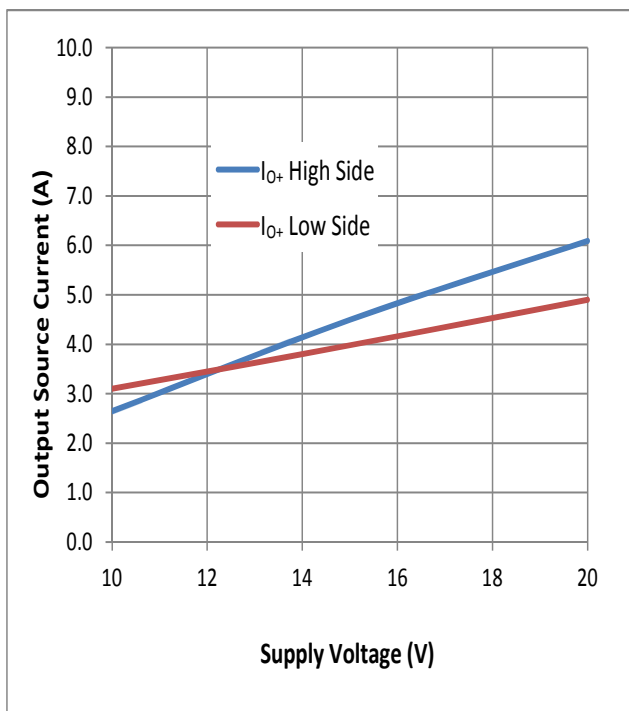


Figure 16. Output Source Current vs. Temperature

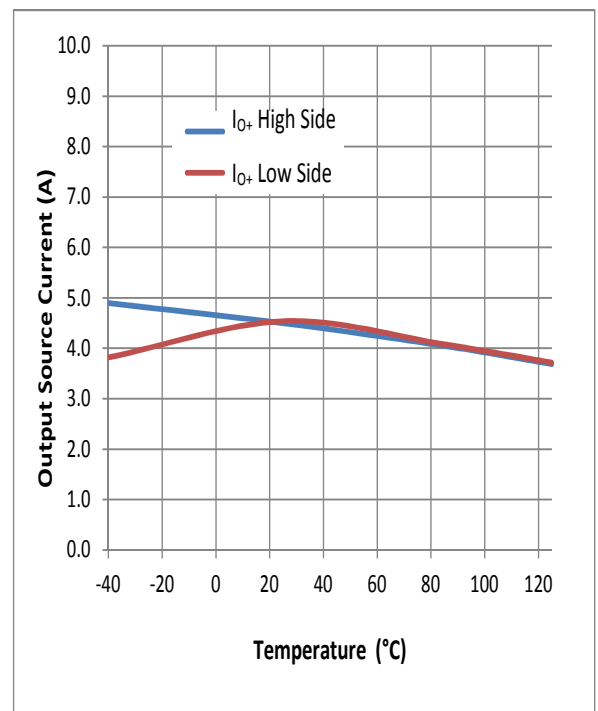


Figure 17. Output Sink Current vs. Supply Voltage

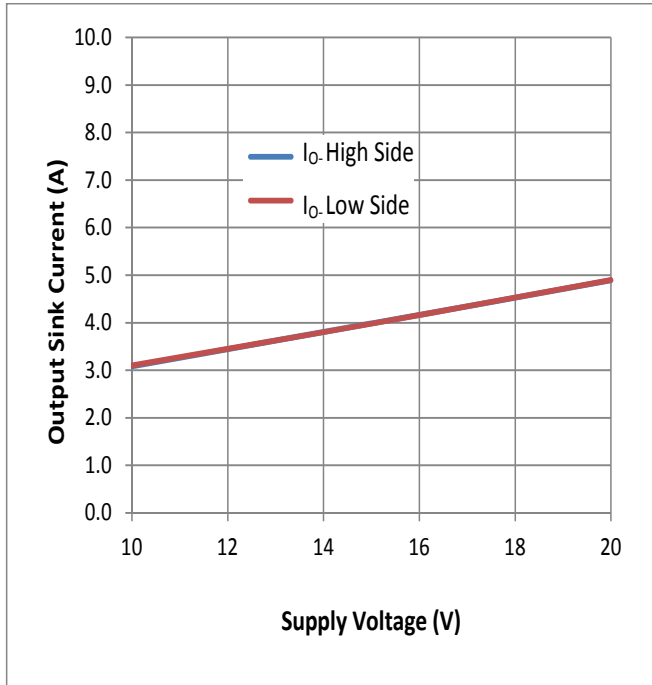


Figure 18. Output Sink Current vs. Temperature

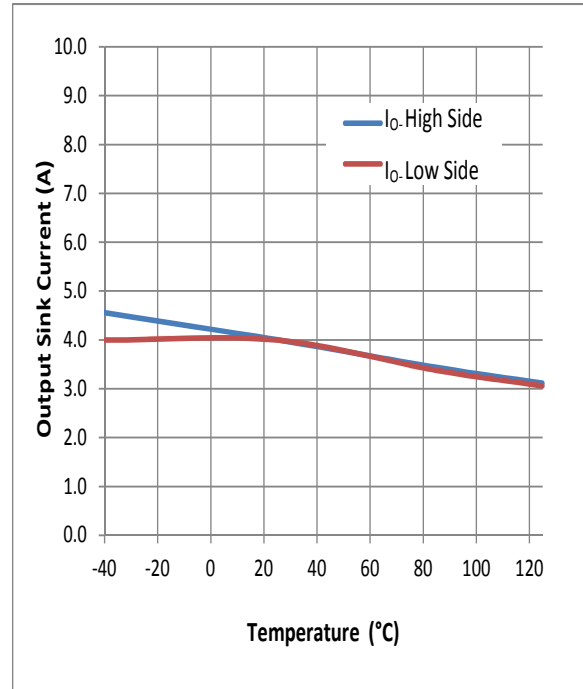


Figure 19. Quiescent Current vs. Supply Voltage

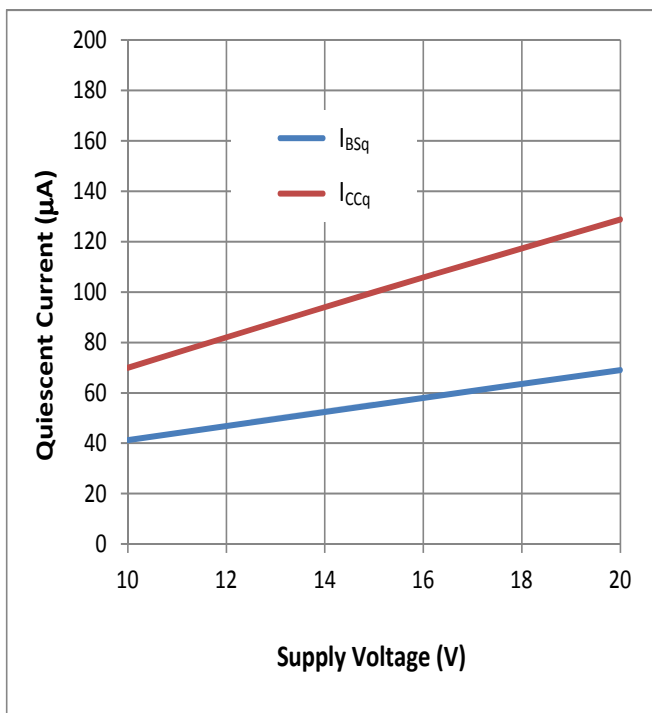


Figure 20. Quiescent Current vs. Temperature

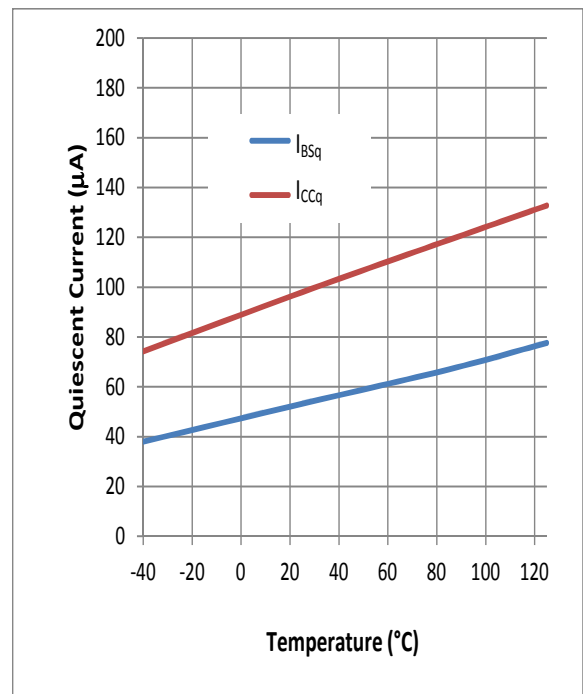


Figure 21. Logic 1 Input Voltage vs. Supply Voltage

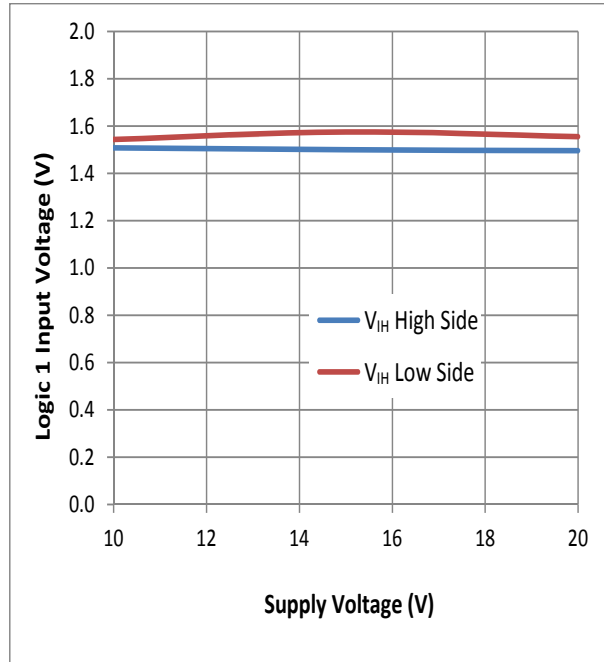


Figure 22. Logic 1 Input Voltage vs. Temperature

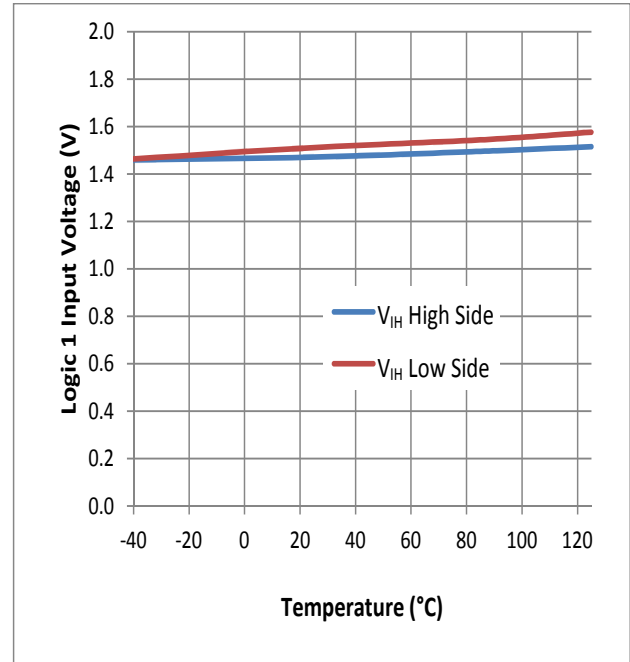


Figure 23. Logic 0 Input Voltage vs. Supply Voltage

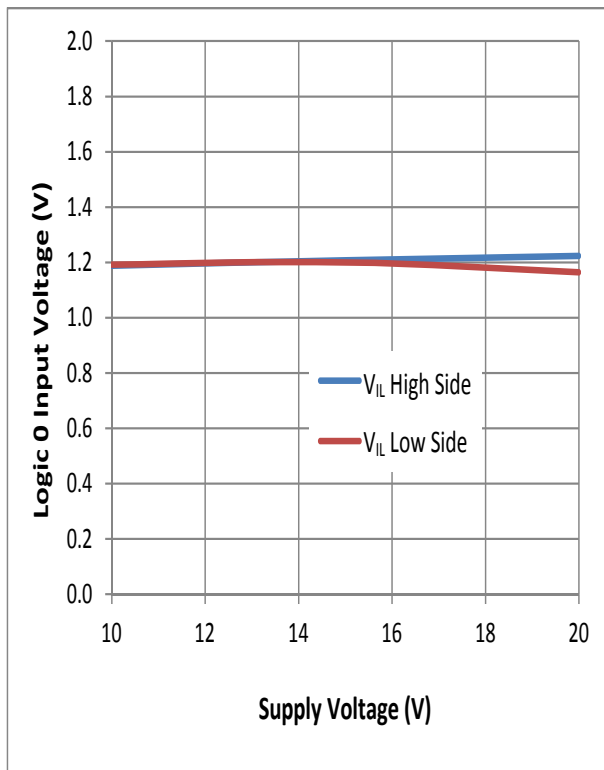


Figure 24. Logic 0 Input Voltage vs. Temperature

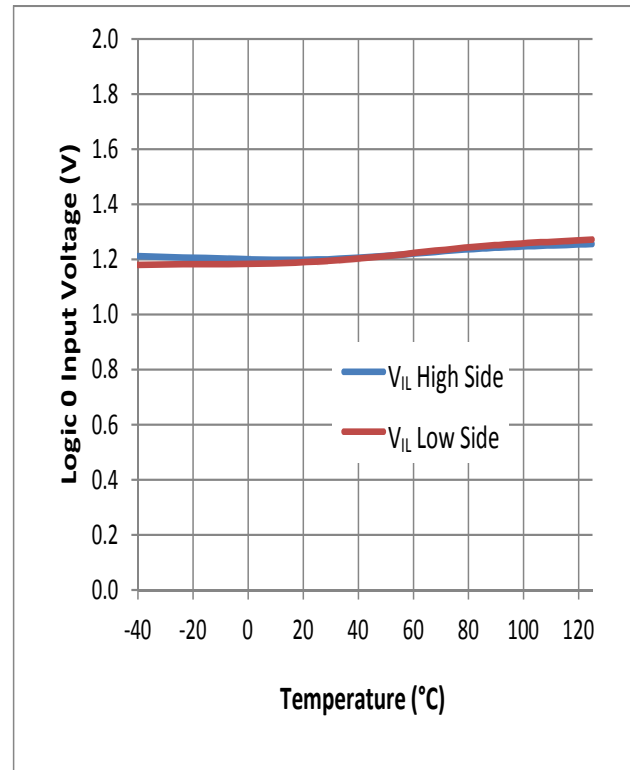


Figure 25. V_{CC} UVLO vs. Temperature

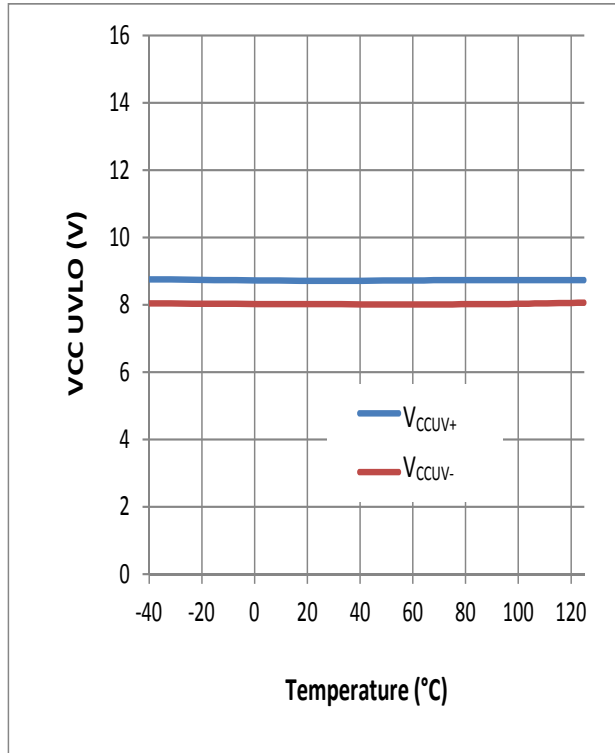


Figure 26. V_{BS} UVLO vs. Temperature

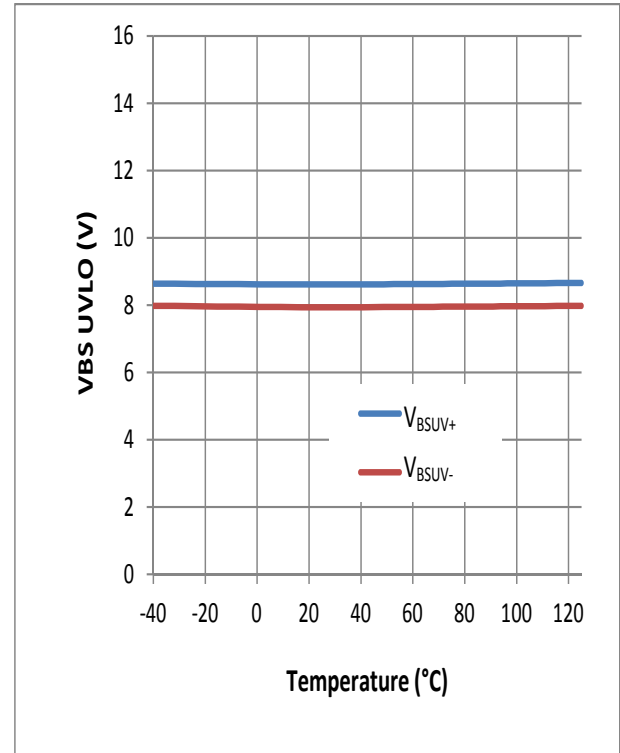
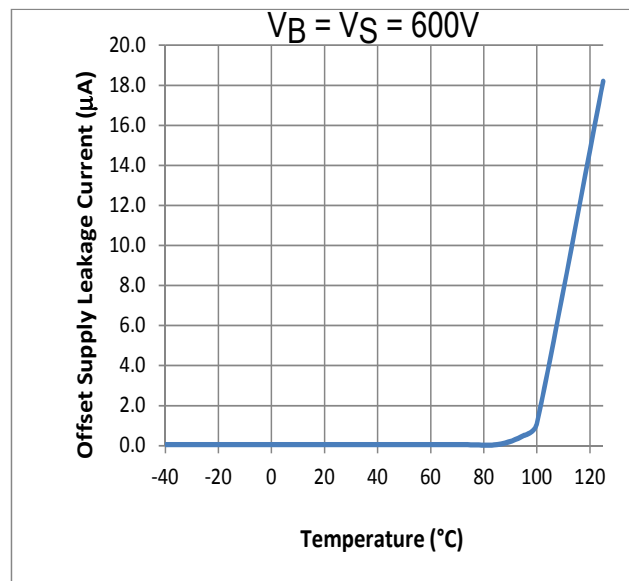


Figure 27. Offset Supply Leakage Current Temperature



4 Manufacturing Information

4.1 Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. Littelfuse Integrated Circuits Division classified all of its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** rating as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
LF21904N	MSL3

4.2 ESD Sensitivity



This product is **ESD Sensitive**, and should be handled according to the industry standard **JESD-625**.

4.3 Reflow Profile

Provided in the table below is the IPC/JEDEC J-STD-020 Classification Temperature (T_c) and the maximum dwell time the body temperature of these surface mount devices may be ($T_c - 5$)°C or greater. The Classification Temperature sets the Maximum Body Temperature allowed for these devices during reflow soldering processes.

Device	Classification Temperature(T_c)	Dwell Time (t_p)	Max Reflow Cycles
LF21904N	260°C	30 seconds	3

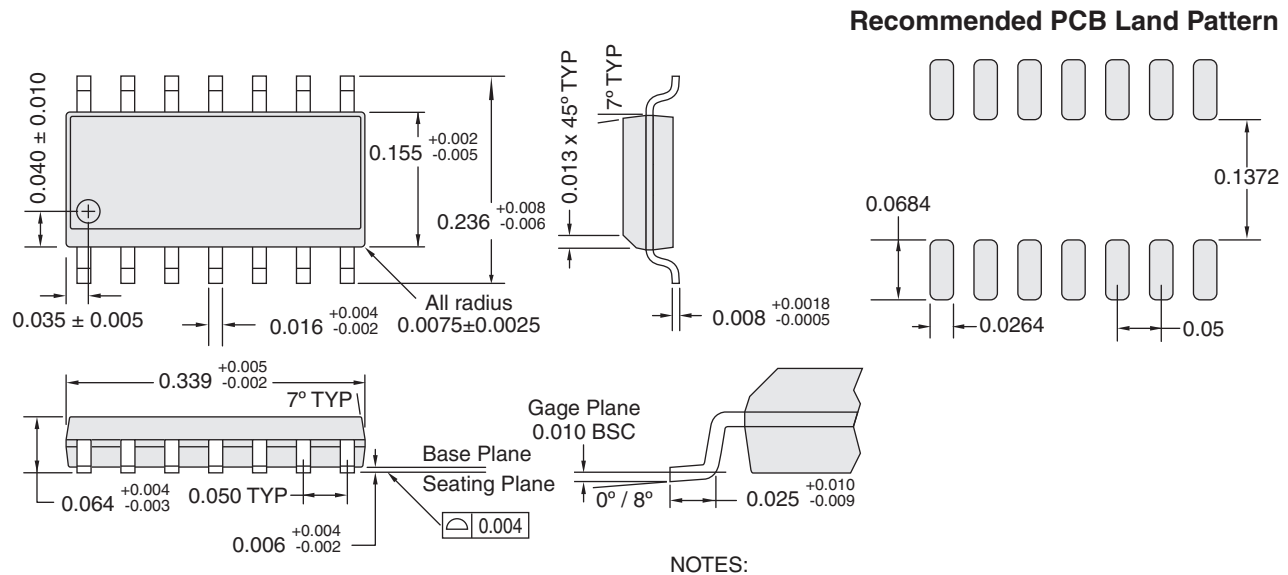


4.4 Board Wash

Littelfuse recommends the use of no-clean flux formulations. Board washing to reduce or remove flux residue following the solder reflow process is acceptable provided proper precautions are taken to prevent damage to the device. These precautions include but are not limited to: using a low pressure wash and providing a follow up bake cycle sufficient to remove any moisture trapped within the device due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.



5 Package Dimensions: SOIC(N)-14



Important Notice

Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at <https://www.littelfuse.com/disclaimer-electronics>.

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